

RD74LVC08B

Quad. 2-input AND Gates

REJ03D0221-0100Z Rev.1.00 May 11, 2004

Description

The RD74LVC08B has four 2-input AND gates in a 14 pin package. Low voltage and high speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High output current $\pm 4 \text{ mA} (@V_{CC} = 1.65 \text{ V})$

 $\pm 8 \text{ mA } (@V_{CC} = 2.3 \text{ V})$

 $\pm 12 \text{ mA } (@V_{CC} = 2.7 \text{ V})$

 $\pm 24 \text{ mA} (@V_{CC} = 3.0 \text{ V to } 5.5 \text{ V})$

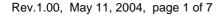
• Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC08BFPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
RD74LVC08BTELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

Function Table

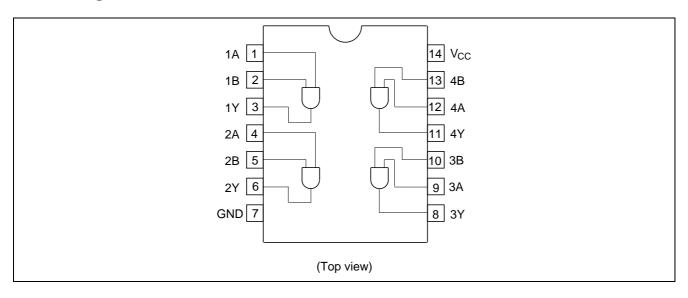
Inp		
Α	В	Output Y
L	L	L
Н	L	L
L	Н	L
Н	Н	Н

H: High levelL: Low level





Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{CC}	-0.5 to 7.0	V	
Input diode current	I _{IK}	-50	mA	V _I = -0.5 V
Input voltage	Vı	-0.5 to 7.0	V	
Output diode current	I _{OK}	-50	mA	V _O = -0.5 V
		50	mA	$V_{O} = V_{CC} + 0.5 \text{ V}$
Output voltage	Vo	-0.5 to V _{CC} +0.5	V	
Output current	Io	±50	mA	
V _{CC} , GND current / pin	I _{CC} or I _{GND}	100	mA	
Storage temperature	Tstg	-65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{cc}	1.5 to 5.5	V	Data hold
		1.65 to 5.5		At operation
Input / Output voltage	Vı	0 to 5.5	V	A, B
	Vo	0 to V _{CC}		Υ
Operating temperature	Та	-40 to 85	°C	
Output current	Іон	-4	mA	V _{CC} = 1.65 V
		-8		$V_{CC} = 2.3 \text{ V}$
		-12		V _{CC} = 2.7 V
		-24		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$
	I _{OL}	4		V _{CC} = 1.65 V
		8		$V_{CC} = 2.3 \text{ V}$
		12		$V_{CC} = 2.7 \text{ V}$
		24		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$
Input rise / fall time*1	t _r , t _f	20	ns/V	V _{CC} = 1.65 V to 2.7 V
		10		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

			Ta = -40 to 85°C			
Item	Symbol	V _{CC} (V)	Min Max		Unit	Test Conditions
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.65	_	V	
		2.3 to 2.7	1.7			
		2.7 to 3.6	2.0	_		
		4.5 to 5.5	V _{CC} ×0.7	_		
	V _{IL}	1.65 to 1.95	_	V _{CC} ×0.35		
		2.3 to 2.7	_	0.7		
		2.7 to 3.6	_	0.8		
		4.5 to 5.5	_	V _{CC} ×0.3		
Output voltage	V _{OH}	1.65 to 5.5	V _{CC} -0.2	_	V	I _{OH} = -100 μA
		1.65	1.2			$I_{OH} = -4 \text{ mA}$
		2.3	1.7			$I_{OH} = -8 \text{ mA}$
		2.7	2.2	_		I _{OH} = -12 mA
		3.0	2.4	_		
		3.0	2.2	_		$I_{OH} = -24 \text{ mA}$
		4.5	3.8	_		
	V_{OL}	1.65 to 5.5	_	0.2		I _{OL} = 100 μA
		1.65	_	0.45		I _{OL} = 4 mA
		2.3	_	0.7		I _{OL} = 8 mA
		2.7	_	0.4		I _{OL} = 12 mA
		3.0	_	0.55		I _{OL} = 24 mA
		4.5	_	0.55		
Input current	I _{IN}	0 to 5.5		±5.0	μΑ	V _{IN} = 5.5 V or GND
Quiescent supply current	Icc	2.7 to 3.6		±5.0	μΑ	V _{IN} = 3.6 V to 5.5 V
		2.7 to 5.5		5.0		$V_{IN} = V_{CC}$ or GND
	ΔI_{CC}	2.7 to 3.6	_	500		V_{IN} = one input at (V_{CC} -0.6)V, other inputs at V_{CC} or GND

Switching Characteristics

			Ta = -40 to 85°C				From	То
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	1.8±0.15	1.0	_	9.8	ns	A or B	Υ
	t _{PHL}	2.5±0.2	1.0	_	6.9			
		2.7	1.0	_	4.8			
		3.3±0.3	1.0	_	4.1			
		5.0±0.5	1.0	_	3.5			
Between output pins skew*1	t _{OSLH}	1.8±0.15	_	_	_	ns		
	t _{OSHL}	2.5±0.2	_	_	_			
		2.7	_	_	_			
		3.3±0.3	_	_	1.0			
		5.0±0.5	_	_	1.0			
Input capacitance	C _{IN}	3.3	_	5.0	_	pF		

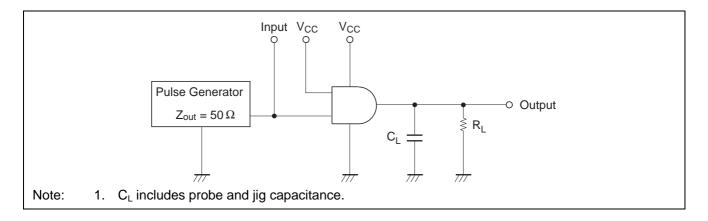
Note: 1. This parameter is characterized but not tested.

 $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

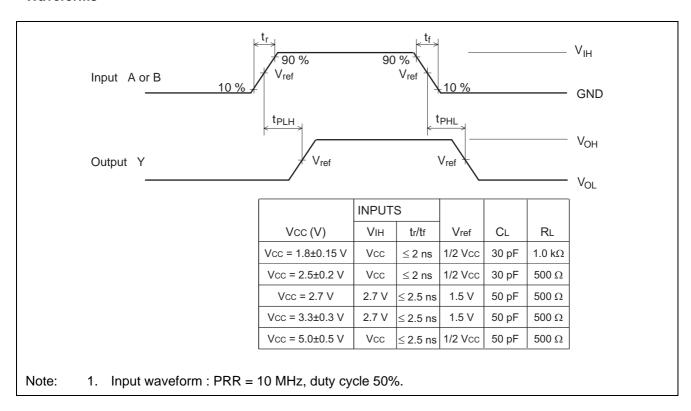
Operating Characteristics

			Ta = 25°C				
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test conditions
Power dissipation Capacitance	C _{PD}	1.8	_	10	_	pF	f = 10 MHz
		2.5	_	12	_		
		3.3	_	12	_		
		5.0	_	15	_		

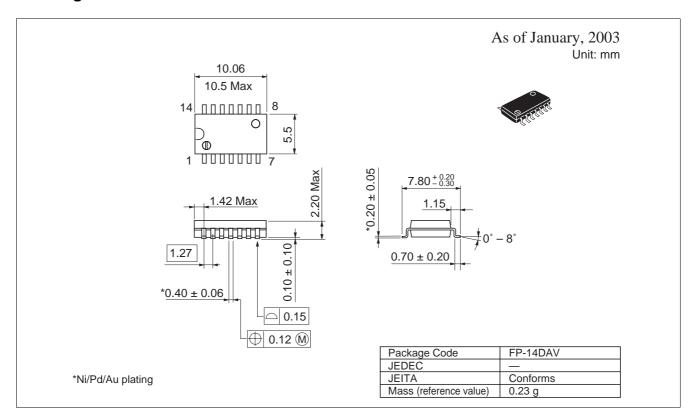
Test Circuit

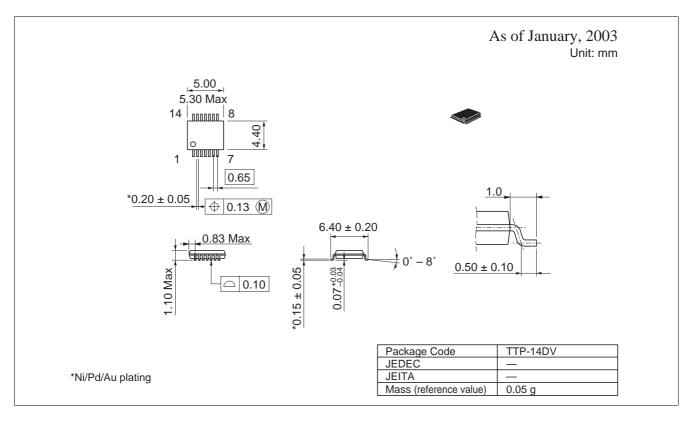


Waveforms



Package Dimensions





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